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SEMICONDUCTOR®

FGPF10N60UNDF 600 V, 10 A Short Circuit Rated IGBT

Features

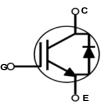
- Short Circuit Rated 10us
- High Current Capability
- High Input Impedance
- Fast Switching
- RoHS Compliant

September 2013

Applications

• Sewing Machine, CNC, Home Appliances, Motor Control





Using advanced NPT IGBT technology, Fairchild's the NPT IGBTs offer the optimum performance for low-power inverter-

driven applications where low-losses and short-circuit rugged-

ness features are essential, such as sewing machine, CNC,

General Description

motor control and home appliances.

Absolute Maximum Ratings

Symbol	Descriptio	n	Ratings	Unit
V _{CES}	Collector to Emitter Voltage		600	V
V _{GES}	Gate to Emitter Voltage		±20	V
I _C	Collector Current	@ T _C = 25°C	20	A
10	Collector Current	@ T _C = 100 ^o C	10	A
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	30	A
IF	Diode Forward Current	@ T _C = 25°C	10	A
	Diode Forward Current	@ T _C = 100 ^o C	5	A
P _D	Maximum Power Dissipation	@ T _C = 25°C	42	W
. D	Maximum Power Dissipation	@ T _C = 100°C	17	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	3.0	°C/W
$R_{\theta JC}$ (Diode)	(Diode) Thermal Resistance, Junction to Case		5.6	°C/W
$R_{\theta JA}$	_{0JA} Thermal Resistance, Junction to Ambient (PCB Mount)(2)		62.5	°C/W

Notes:

2: Mountde on 1" square PCB (FR4 or G-10 material)

		Package	Reel Size	Таре	Width	Quantity		
		TO-220F	-			50ea		
Electric	al Chai	racteristics of th	ne IGBT _{Tc=}	25°C unless otherwise noted	1			
Symbol		Parameter	Test	t Conditions	Min.	Тур.	Max.	Unit
Off Chanad						•		
Off Charact		to Emitter Breakdown Vol	tage V _{GE} = 0 V,	La = 250 µA	600	-	-	V
BV _{CES}		Cut-Off Current		₆ , V _{GE} = 0 V	-		1	mA
		age Current		$v_{GE} = 0 V$ S, $V_{CE} = 0 V$	-	-	۱ ±10	uA
I _{GES}	J-L Leak	age Current	VGE = VGE	5, VCE – U V	<u> </u>	I -	10	uA
On Charact	eristics							
V _{GE(th)}	G-E Three	shold Voltage	I _C = 10 mA	, $V_{CE} = V_{GE}$	5.5	6.8	8.5	V
			I _C = 10 A, V	′ _{GE} = 15 V	-	2	2.45	V
V _{CE(sat)}	Cel(sat) Collector to Emitter Saturation Voltage		age I _C = 10 A, V T _C = 125°C		-	2.3	-	V
Dynamic Cl	naracteristi	cs						
C _{ies}	Input Cap	acitance			-	517		pF
C _{oes}	Output Ca	apacitance	V _{CE} = 30 V f = 1 MHz	$V_{CE} = 30 V, V_{GE} = 0 V,$	-	65		pF
C _{res}	Reverse ⁻	Transfer Capacitance				20		pF
Switching C	haracterist	ics						
t _{d(on)}	r	Delay Time			-	8.0		ns
t _r	Rise Time	9		V _{CC} = 400 V, I _C = 10 A,		6.3		ns
t _{d(off)}	Turn-Off I	Delay Time	$V_{cc} = 400$			52.2		ns
t _f	Fall Time		R _G = 10 Ω,	V _{GE} = 15 V,	-	19.1	24.8	ns
E _{on}	Turn-On S	Switching Loss	Inductive L	oad, $T_C = 25^{\circ}C$	-	0.15		mJ
E _{off}	Turn-Off S	Switching Loss			-	0.05		mJ
E _{ts}	Total Swit	ching Loss			-	0.2		mJ
t _{d(on)}	Turn-On I	Delay Time			-	8.1		ns
t _r	Rise Time	9			-	7.3		ns
t _{d(off)}	Turn-Off I	Delay Time	V _{CC} = 400	V, I _C = 10 A,	-	55.1		ns
t _f	Fall Time		R _G = 10 Ω,	V _{GE} = 15 V,	-	34.2		ns
E _{on}	Turn-On S	Switching Loss	Inductive L	oad, T _C = 125°C	-	0.22		mJ
E _{off}	Turn-Off S	Switching Loss			-	0.08		mJ
E _{ts}	Total Swit	ching Loss			-	0.3		mJ
T _{sc}	Short Circ	cuit Withstand Time	$V_{CC} = 350$ $R_G = 100 \Omega$ $T_C = 150^{\circ}C$	2, V _{GE} = 15 V,	10	-	- (μs

Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

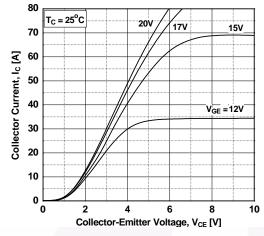
Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Qg	Total Gate Charge		-	37		nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 10 A, V _{GE} = 15 V	-	5		nC
Q _{gc}	Gate to Collector Charge		-	21		nC

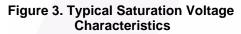
Electrical Characteristics of the Diode $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Test Condition	าร	Min.	Тур.	Max	Unit
V _{FM}	Diode Forward Voltage	۱ _F =	10 A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.8	2.2	V
				$T_{\rm C} = 125^{\rm o}{\rm C}$	-	1.7		
t _{rr}	Diode Reverse Recovery Time	۱ _F =	10 A, dI _F /dt = 200 A/μs	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	37.7		ns
				$T_{\rm C} = 125^{\rm o}{\rm C}$		78.9		
Q _{rr}	Diode Reverse Recovery Charge			$T_{C} = 25^{\circ}C$	-	75		nC
				$T_{C} = 125^{\circ}C$	-	221		

Typical Performance Characteristics







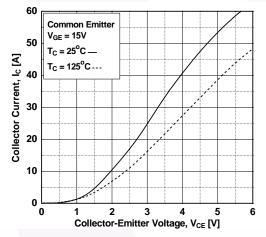


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

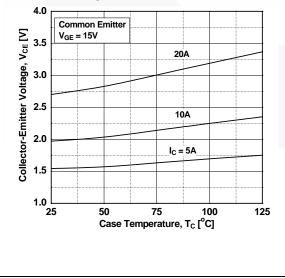


Figure 2. Typical Output Characteristics

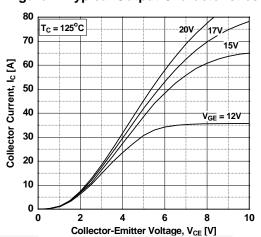


Figure 4. Transfer Characteristics

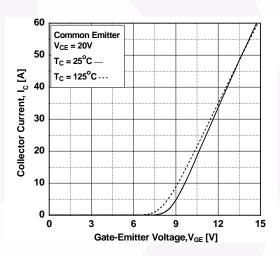
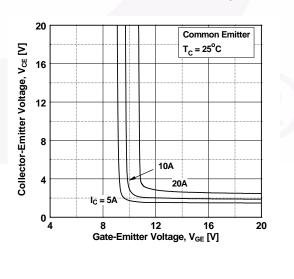


Figure 6. Saturation Voltage vs. V_{GE}



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Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

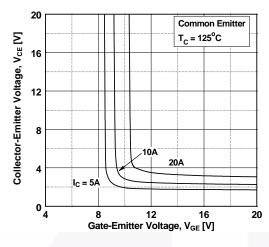
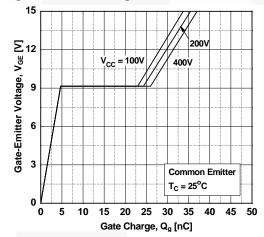


Figure 9. Gate charge Characteristics





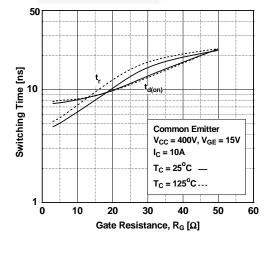


Figure 8. Capacitance Characteristics

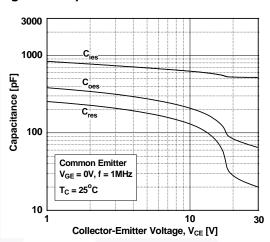
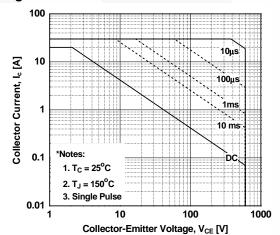
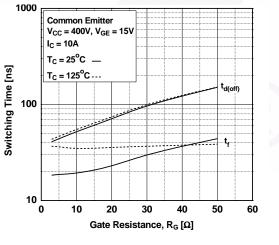


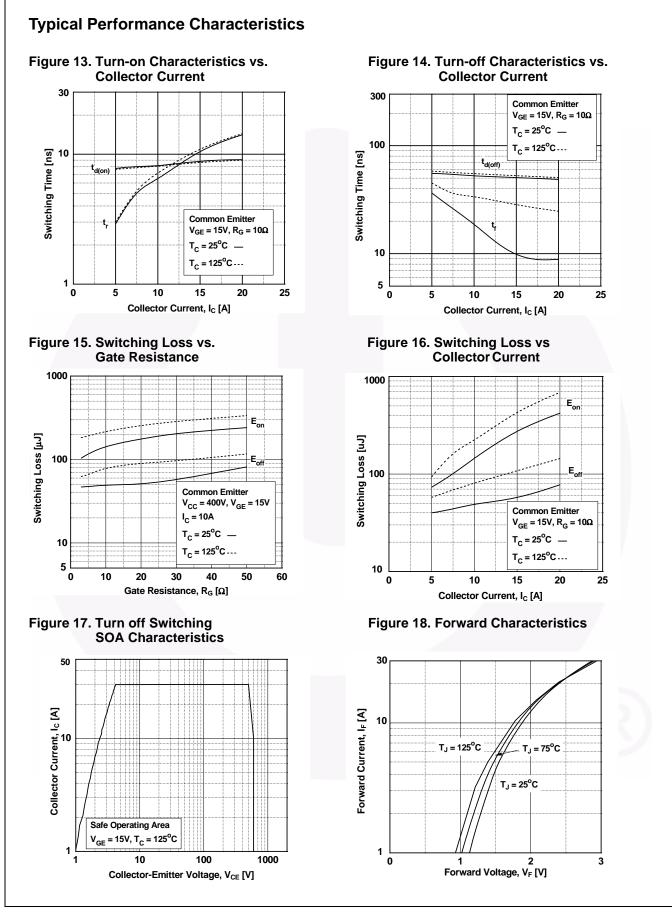
Figure 10. SOA Characteristics



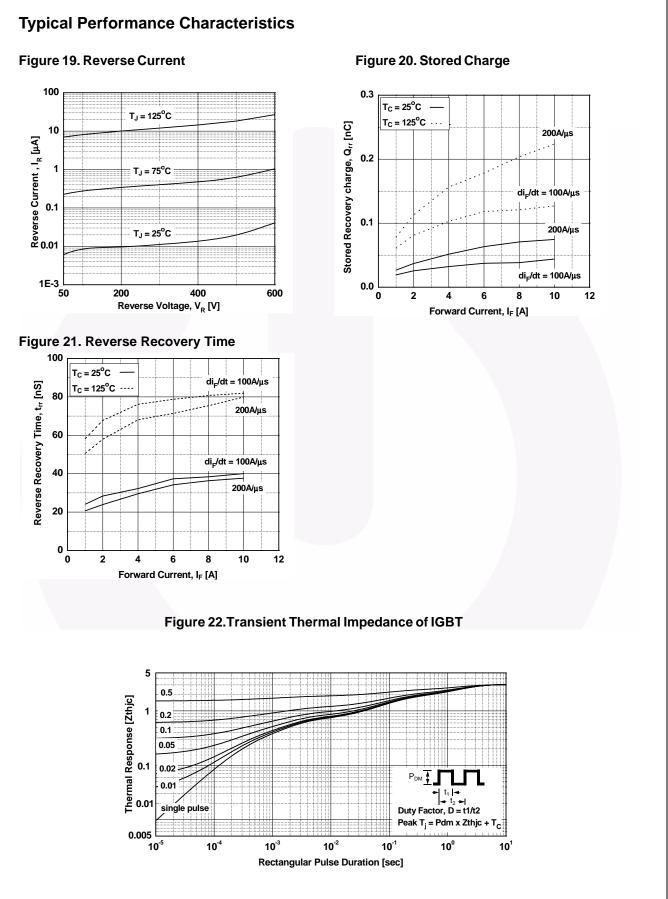




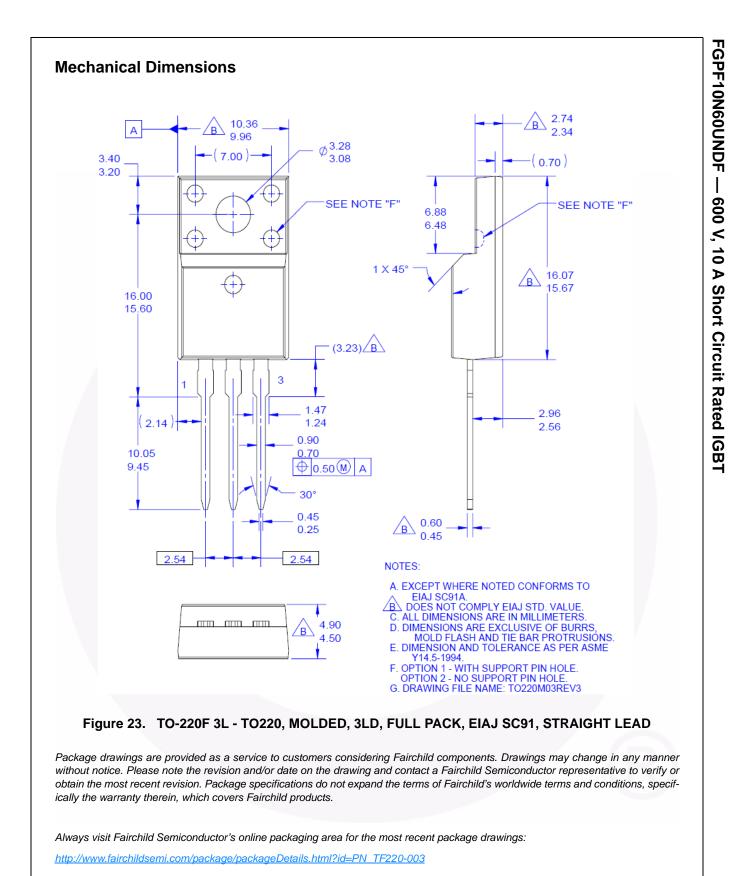
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FGPF10N60UNDF — 600 V, 10 A Short Circuit Rated IGBT



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Dimensions in Millimeters



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